



Nancy-Université

Optical characterization of nanocrystallized AlN:Er films prepared by magnetron sputtering



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Why AlN ?



Facing matrices already studied ...

1/ Physical properties

- Piezo electrical : acousto-optical devices?
- Resistivity to caustic attacks and to corrosion
- Important thermal conductivity
- Wide gap (6,2 eV) : visible LED

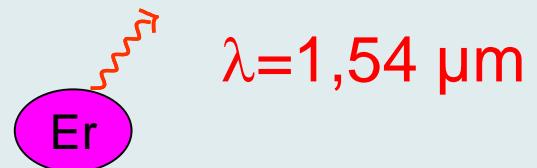
2/ Synthesis possible* with variable morphology with PVD magnetron (transfer to industry)

*

Brien et al. J.Crystal growth 2007 and 2008



Why AlN+Er ?

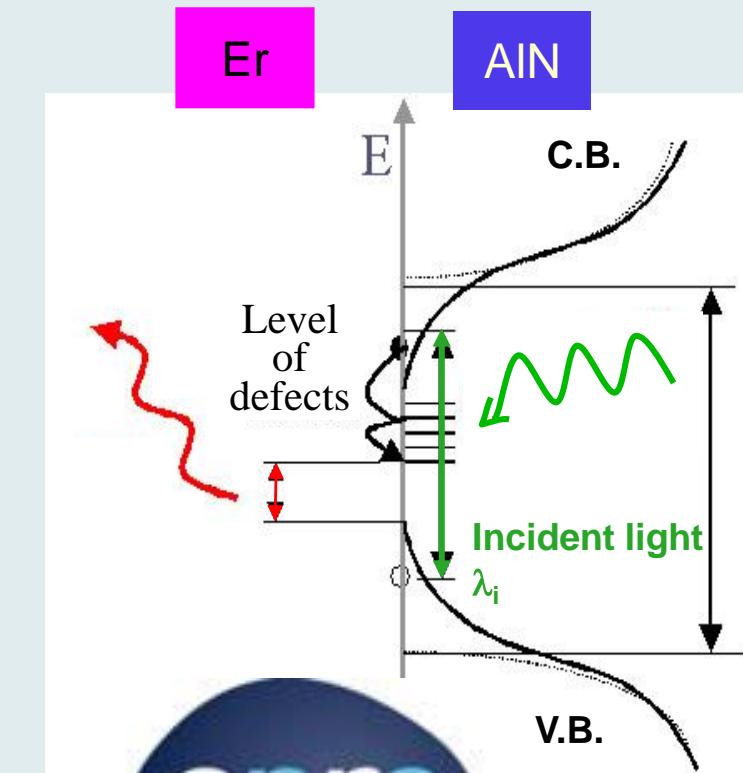
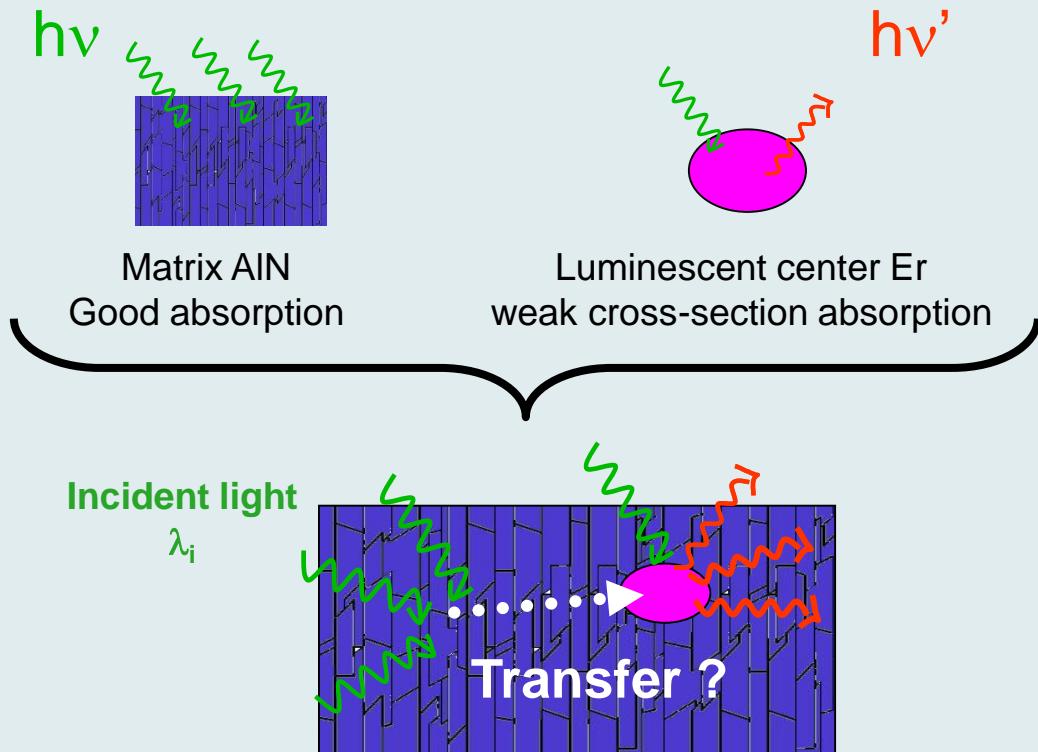


- Photonic applications
 - Telecom domain : Optical interconnection instead of electrical ones
Need of amplifiers and sources at $\lambda=1,54 \mu\text{m}$
- To benefit from the dispersion throughout a matrix
to circumvent a weak cross-section absorption



Take advantage of indirect process:

Introduction of dopant in a collector matrix of variable morphology



Mechanism not fully understood yet

Optimisation of transfer

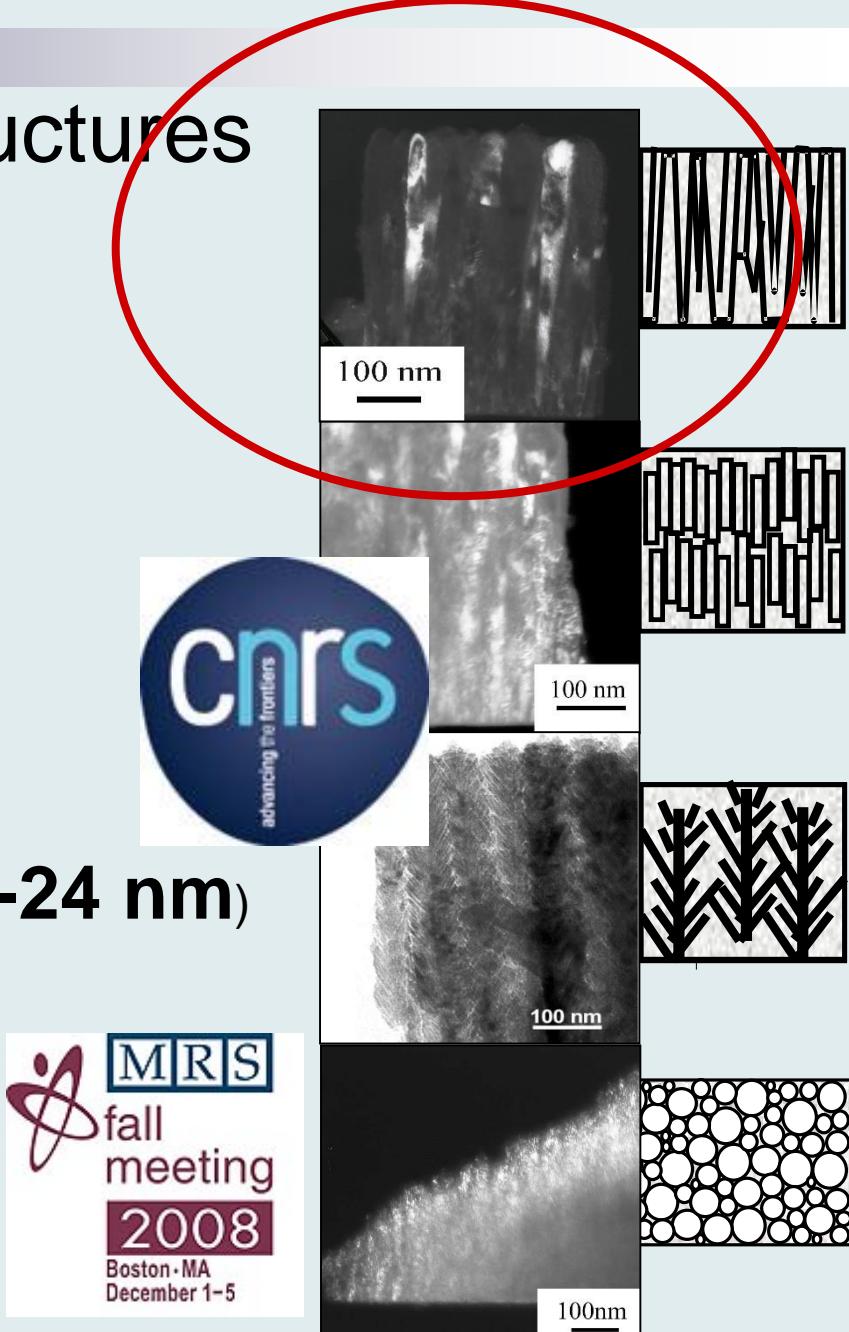
Transfer efficiency => Variable nano-structure

Introduction of levels in matrix thanks to defects ?



4 different AlN:Er nanostructures

- Nano columns (diameter ~ **10-25 nm**)
- Nano rods (diameter ~ **11 nm**)
- Nano columns **feathers** (branch diameter ~ **6-24 nm**)
- Nano grains (diameter ~ **3-20 nm**)

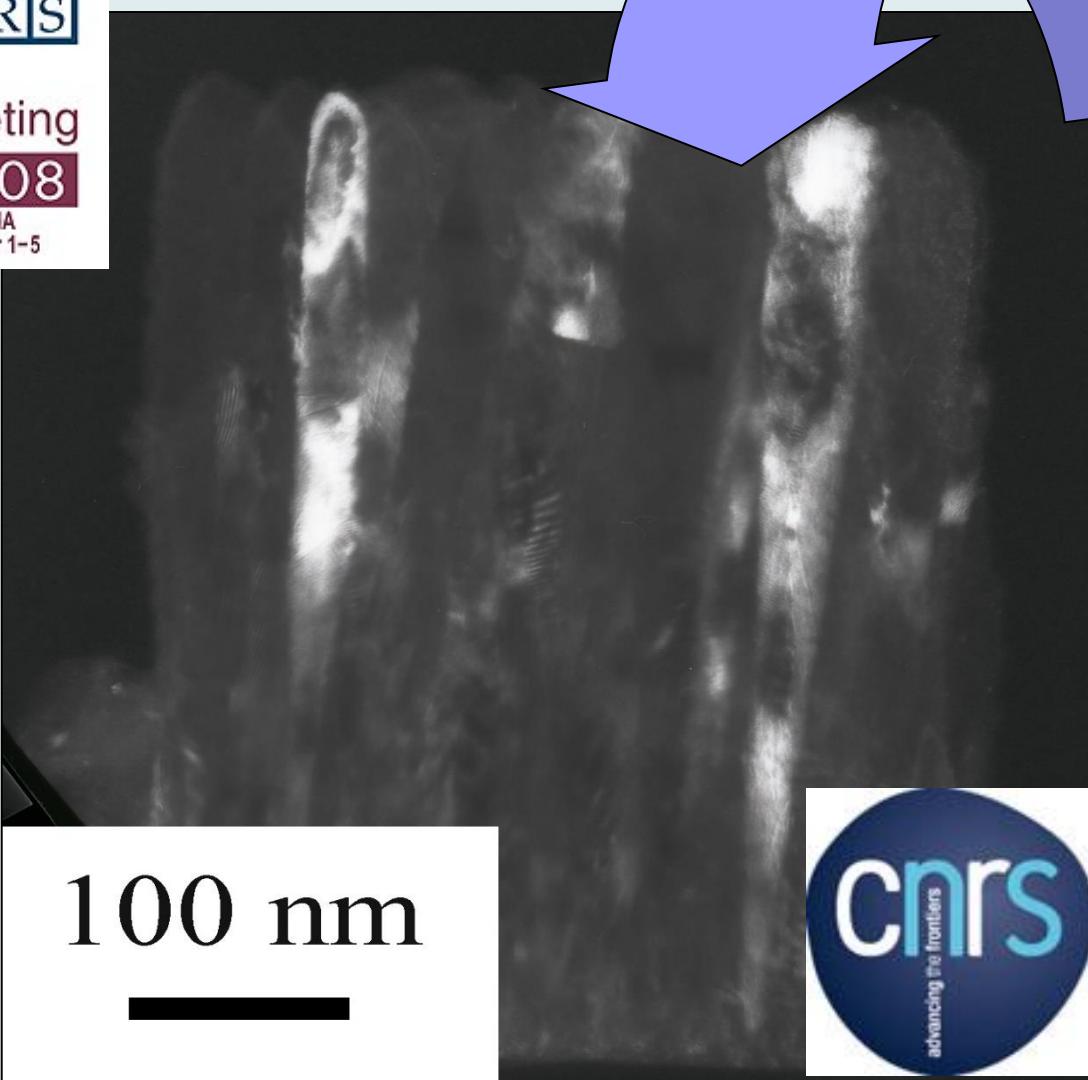


4 different AlN:Er nanostructures

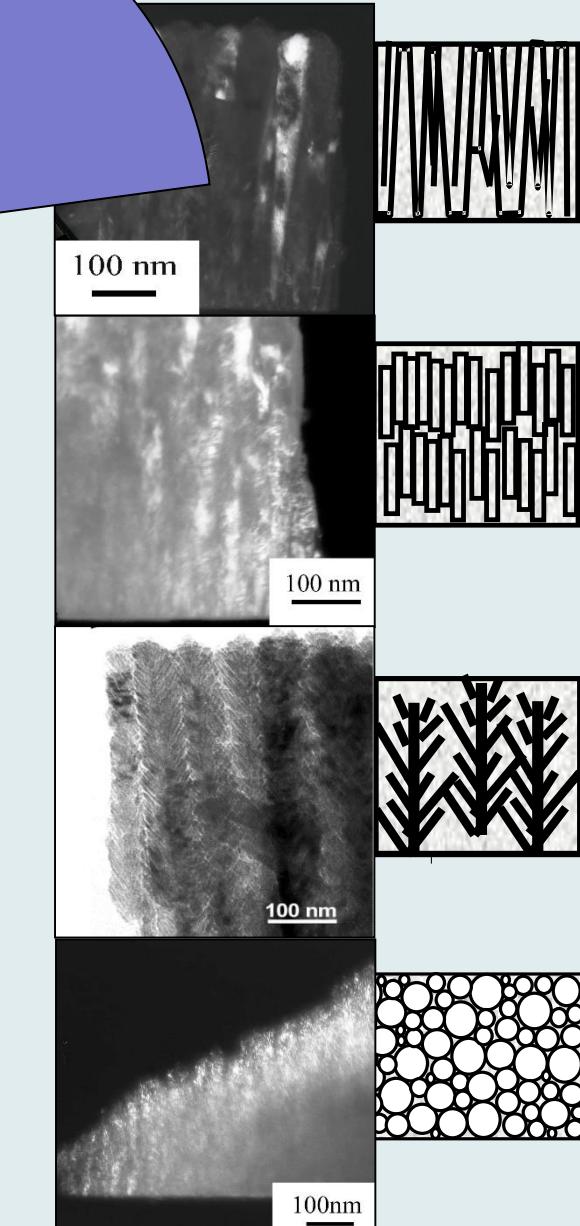


Boston - MA
December 1-5

□ Nano



□ Nano



4 different AlN:Er nanostructures

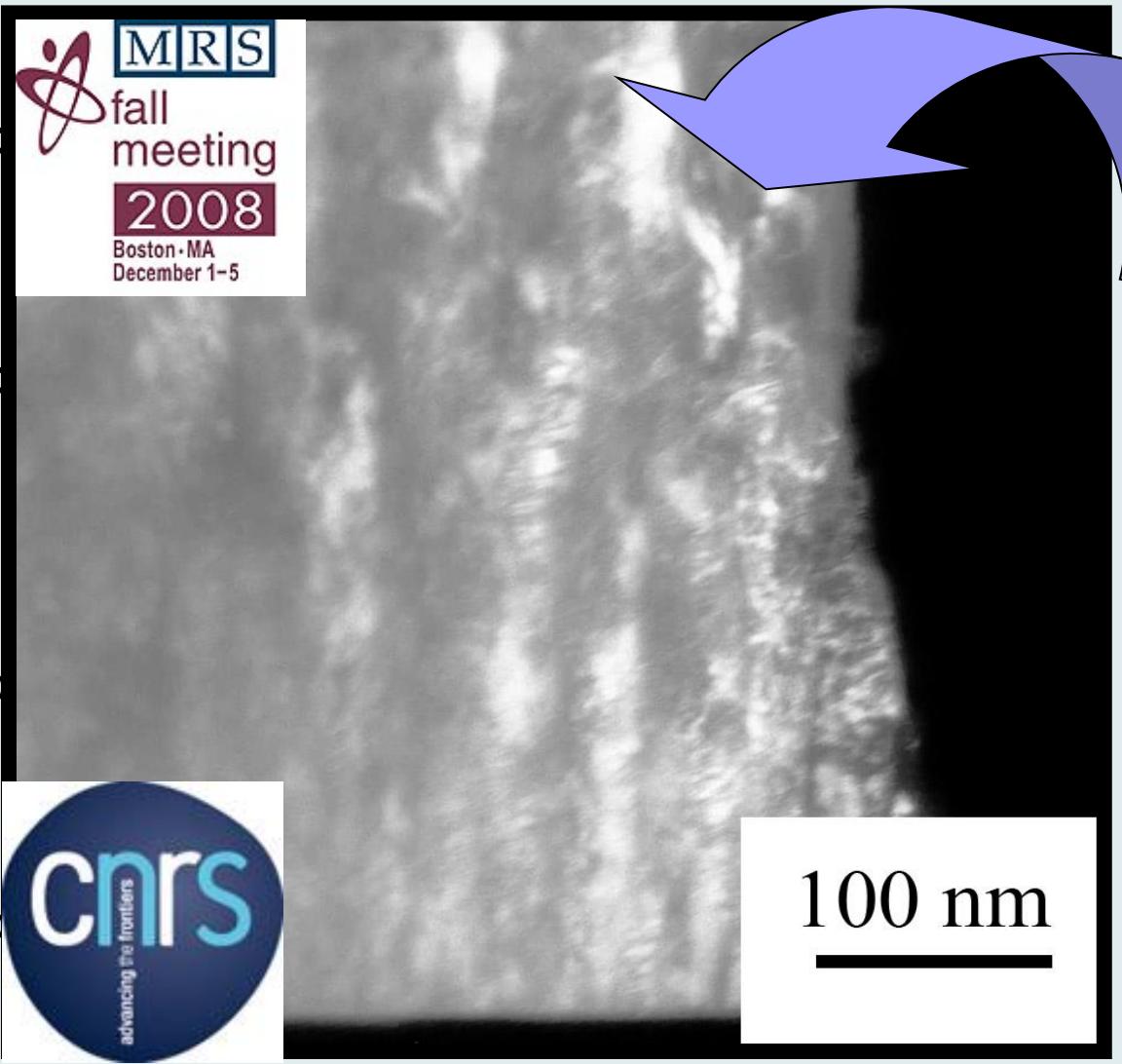
□ Nano



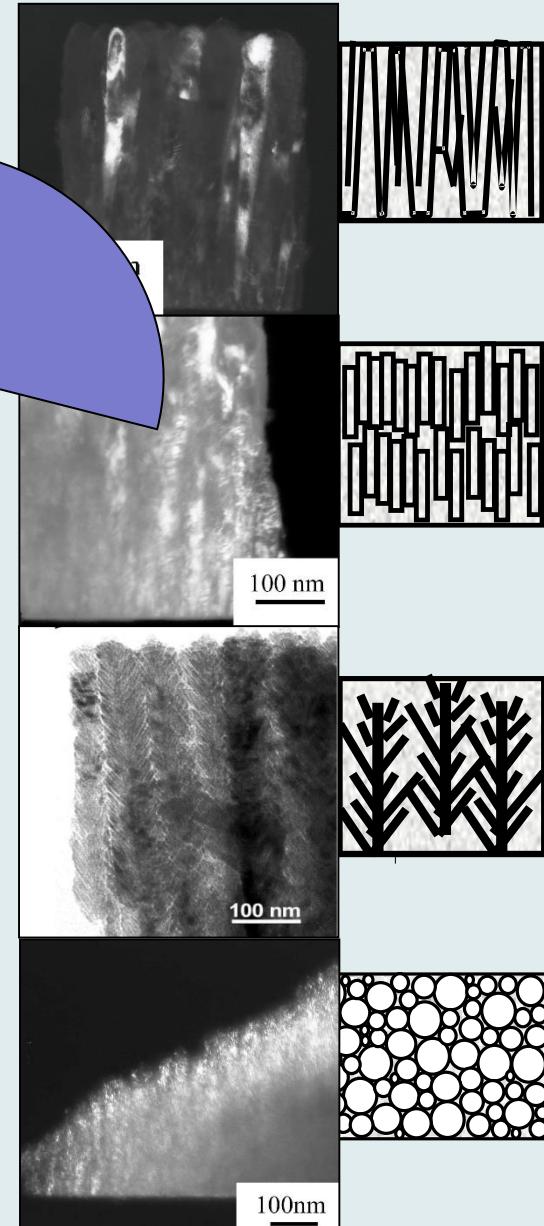
□ Nano



□ Nano

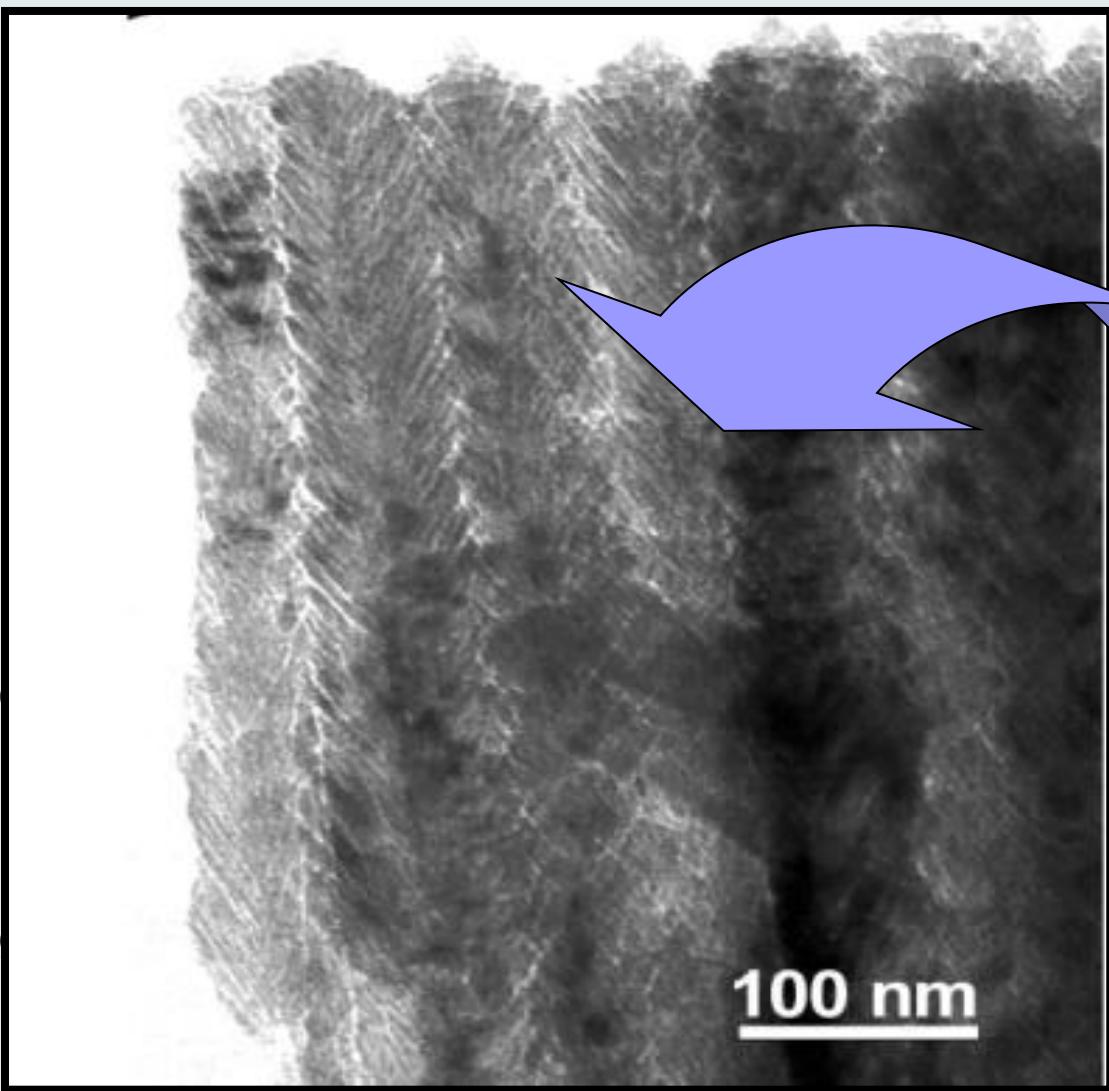


□ Nano

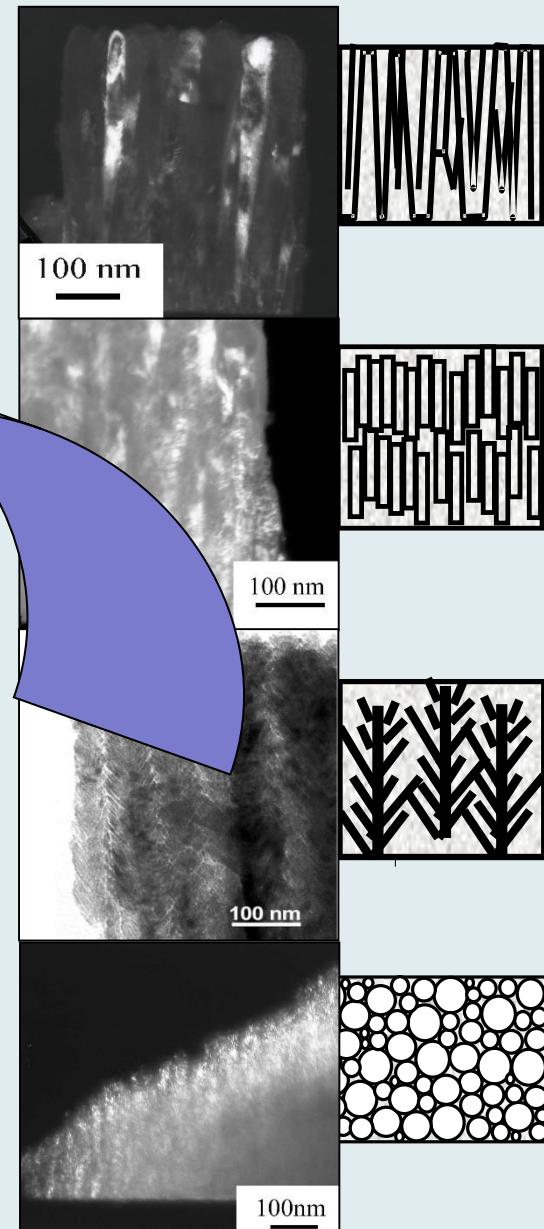


4 different AlN:Er nanostructures

□ Nano

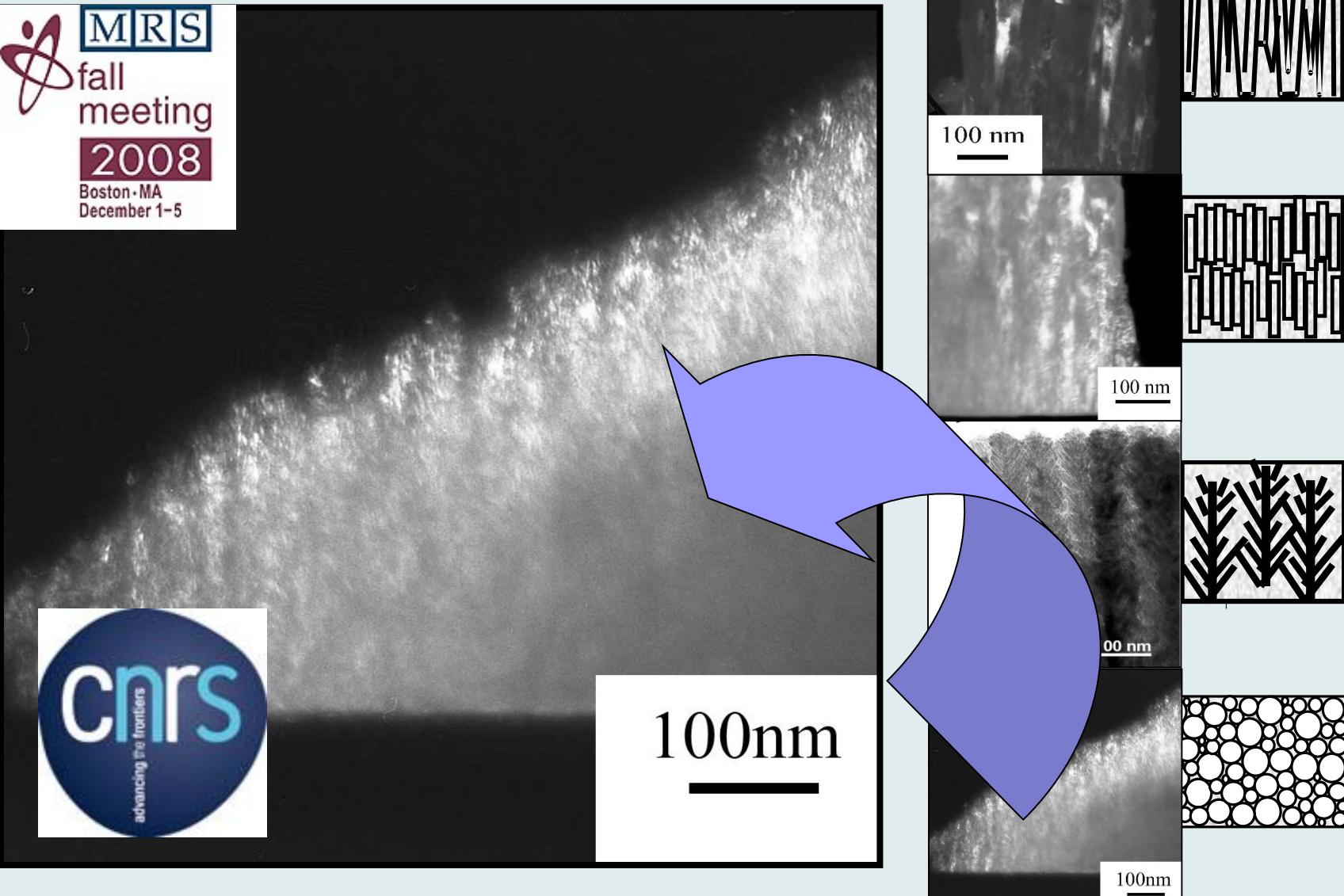
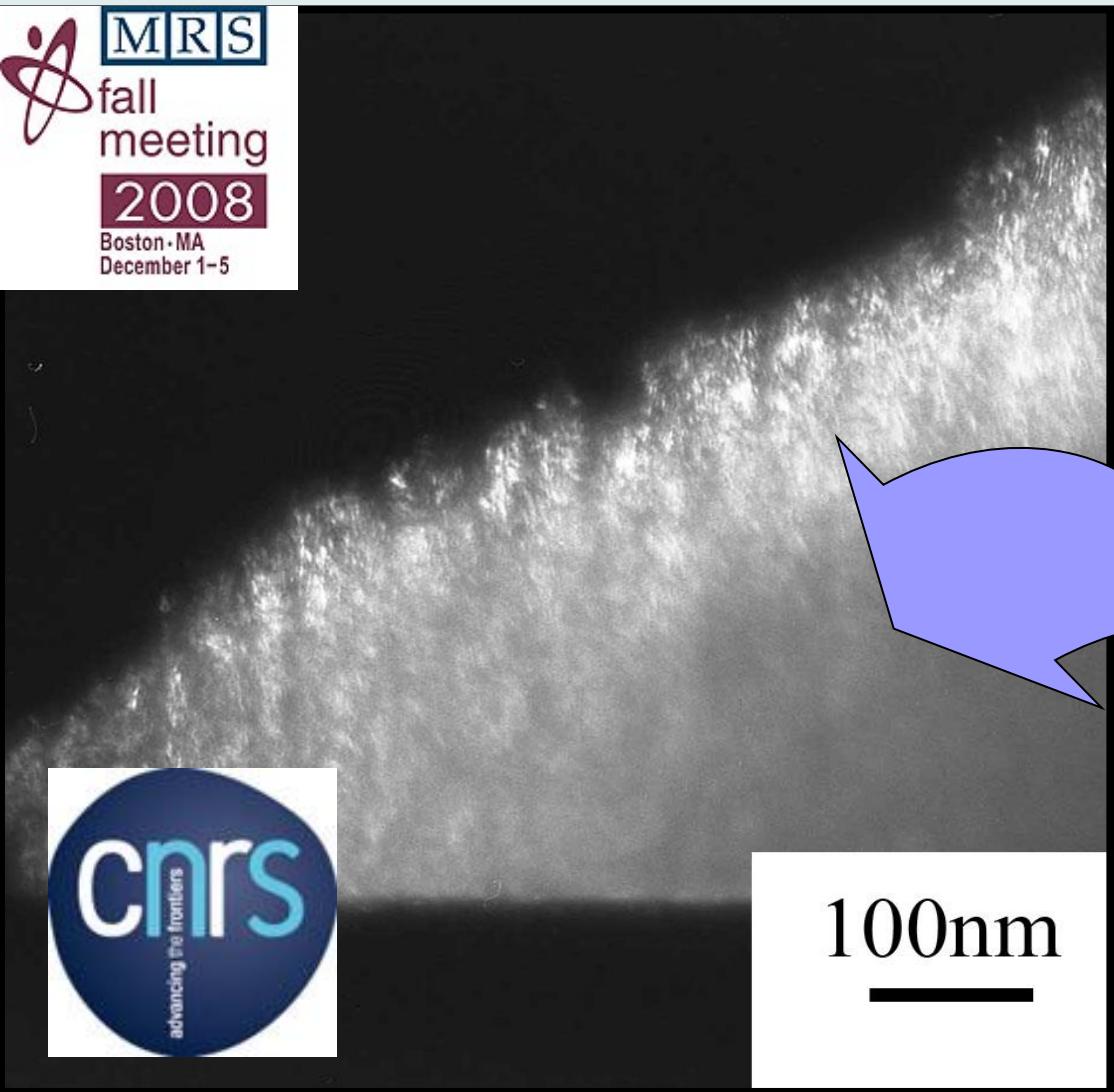


□ Nano



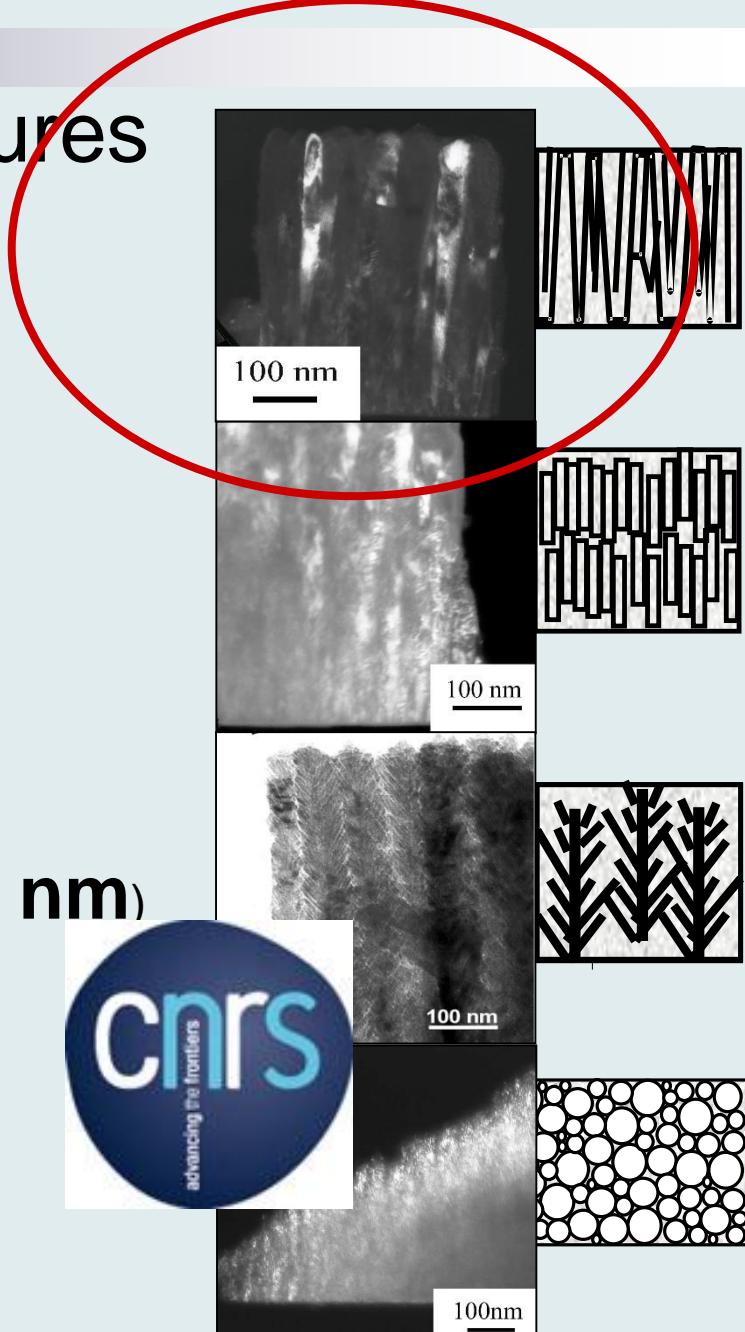
4 different AlN:Er nanostructures

□ Nano

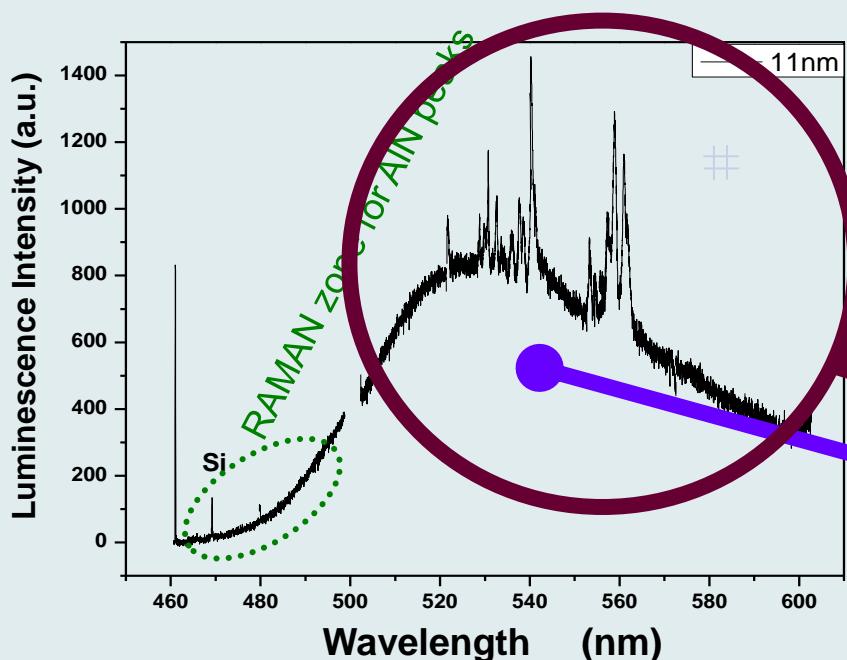


4 different AlN:Er nanostructures

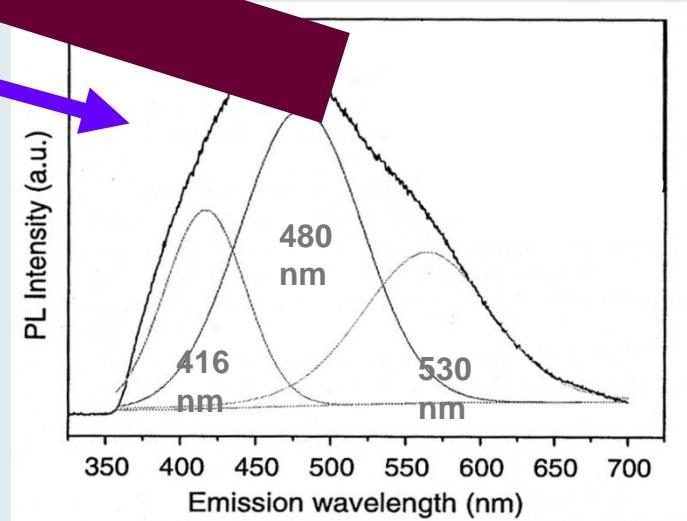
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- Nano rods (diameter ~ **11 nm**)
- Nano columns **feathers** (branch diameter ~ **6-24 nm**)
- Nano grains (diameter ~ **3-20 nm**)



=> VISIBLE high spectral resolution luminescence



ZOOM

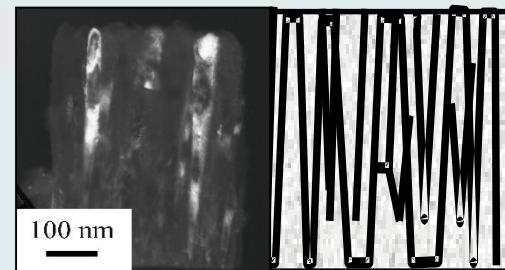


**** Chen 2008



Broad band centered
Around 530 nm:
PL of nano AlN

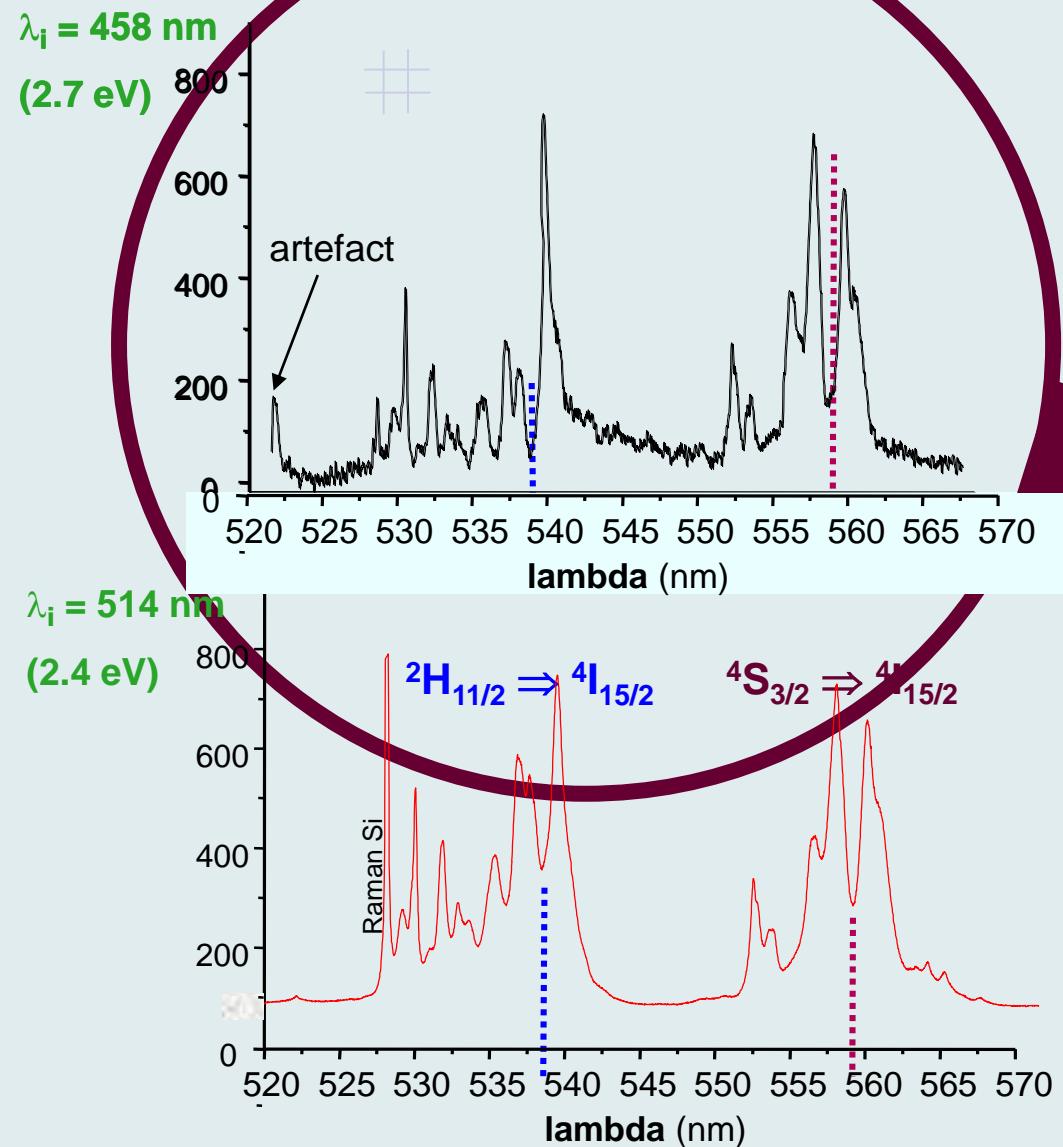
AIN spheres****, whiskers, nanotubes,
crystalline: PL in visible domain same range



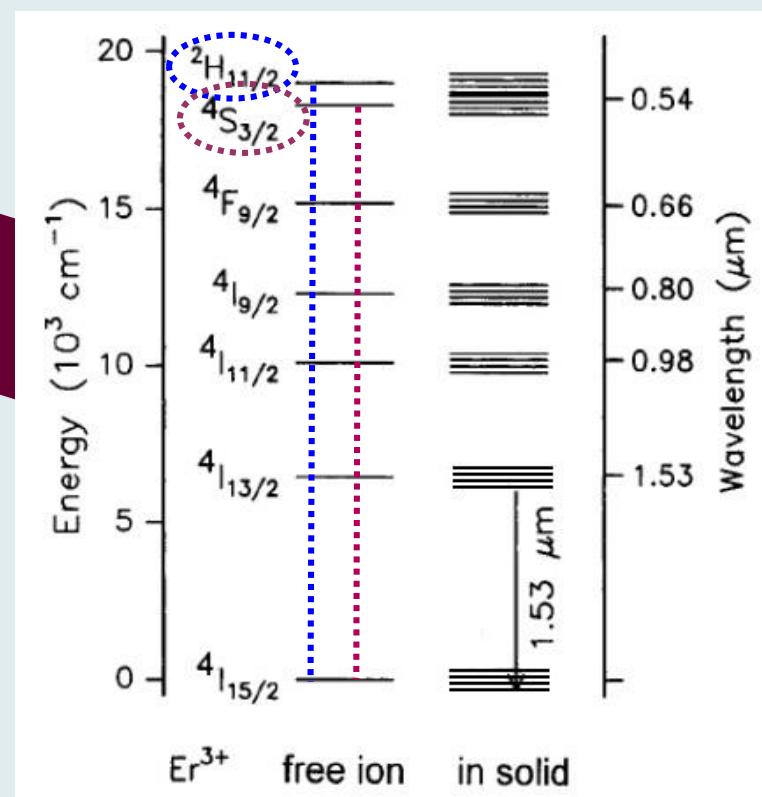
Width of column = 10 - 25 nm
AlN:Er dense film (cross view)



=>VISIBLE high spectral resolution luminescence

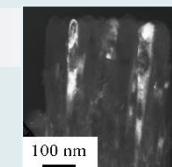


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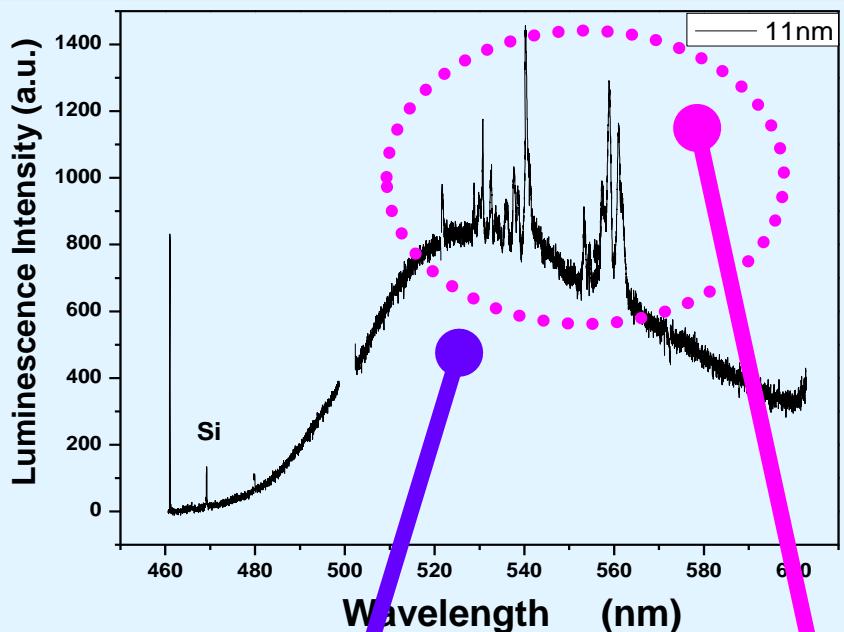


PL of Erbium

=>VISIBLE high spectral resolution luminescence

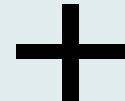


Width of column = 10 - 25 nm
AlN:Er dense film (cross view)



$$\lambda_i = 458 \text{ nm} (2.7 \text{ eV})$$

Broad band at
530 nm



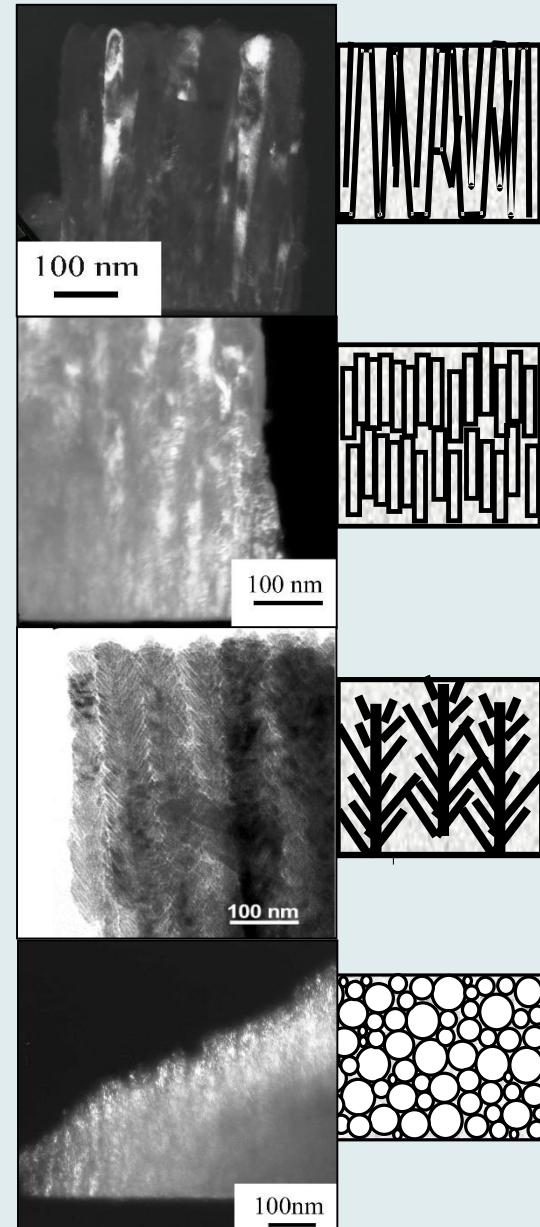
Fine structure
Er



Correspondance :
Transfer ?

4 different AlN:Er nanostructures

- Nano columns (diameter ~ **10-25 nm**)



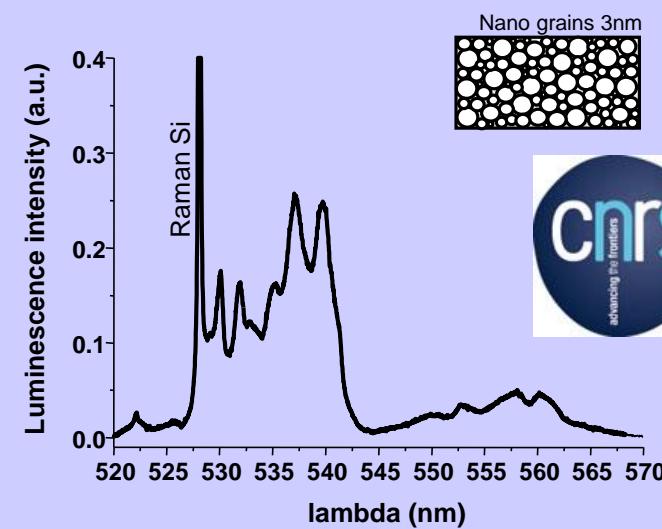
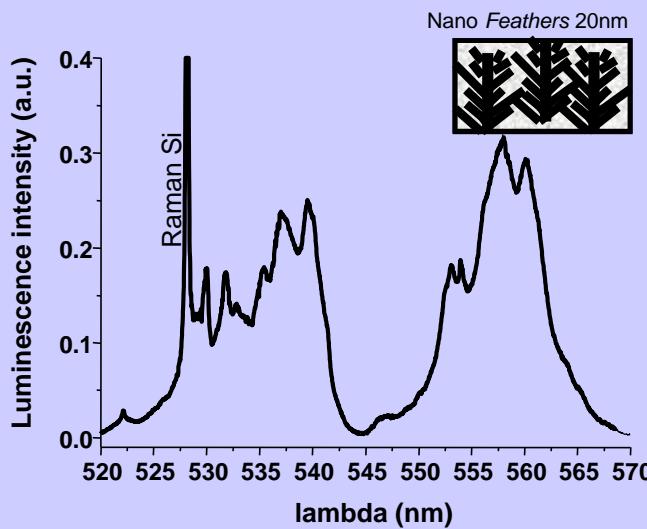
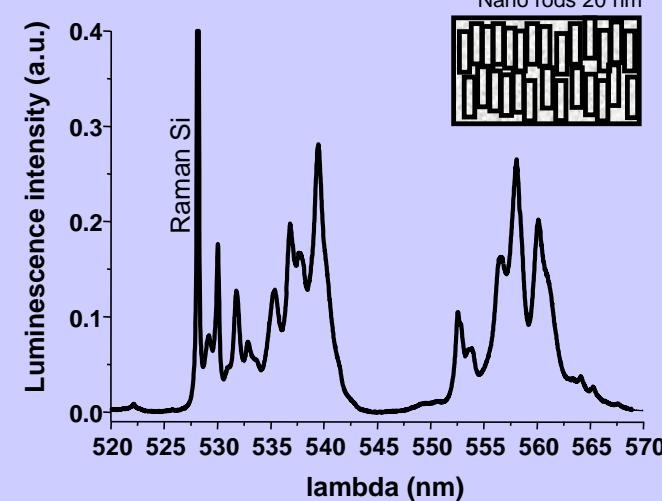
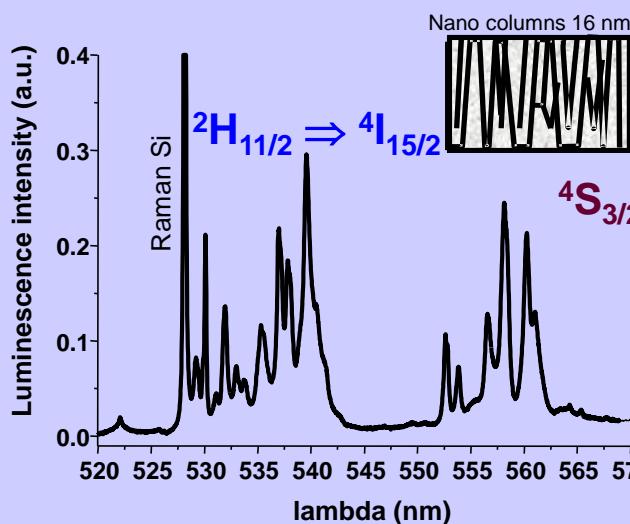
- Nano rods (diameter ~ **11 nm**)

- Nano columns **feathers** (branch diameter ~ **6-24 nm**)

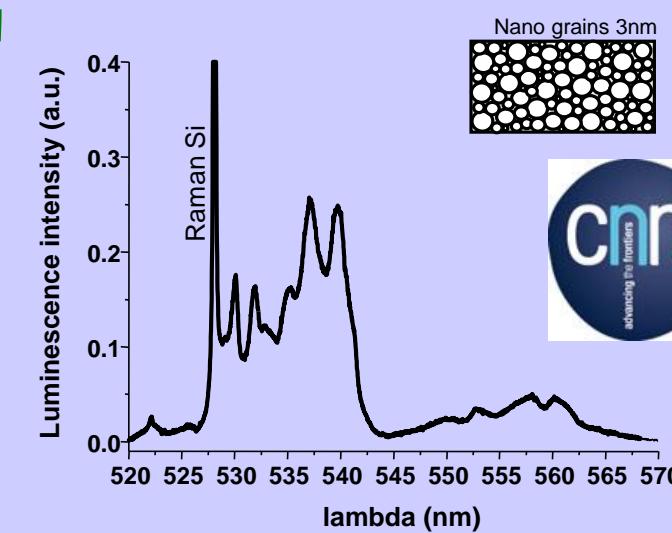
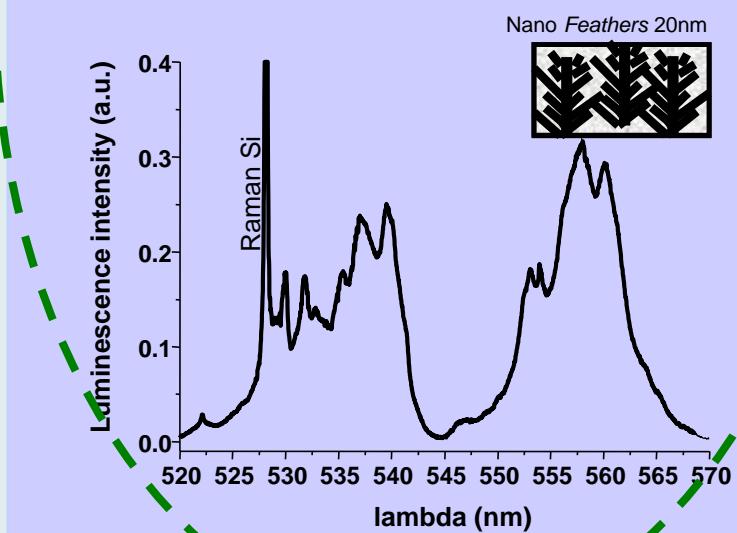
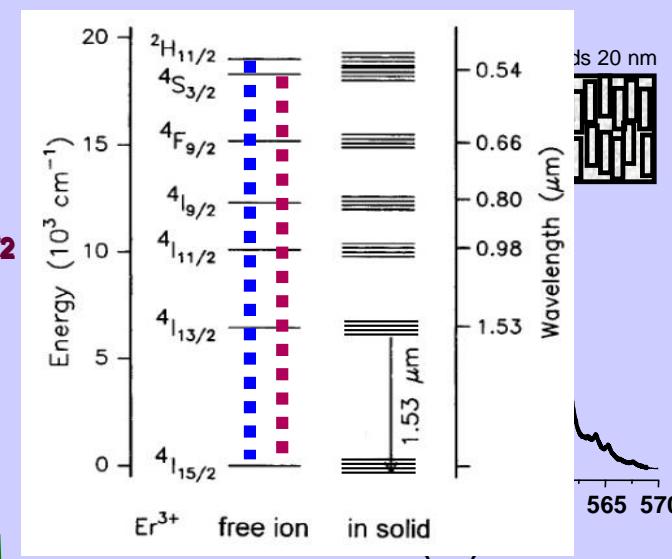
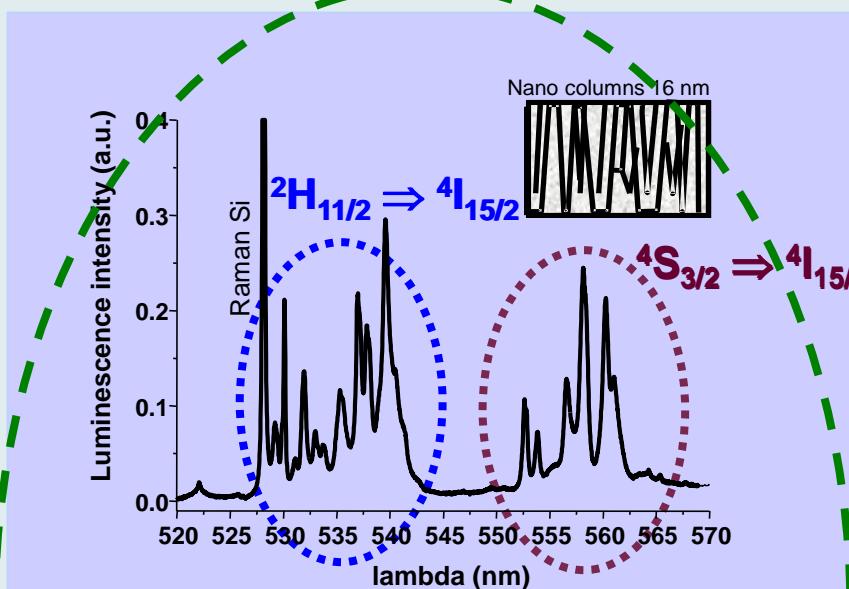


- Nano grains (diameter ~ **3-20 nm**)

Evolution of Er visible luminescence as a function of AlN structure

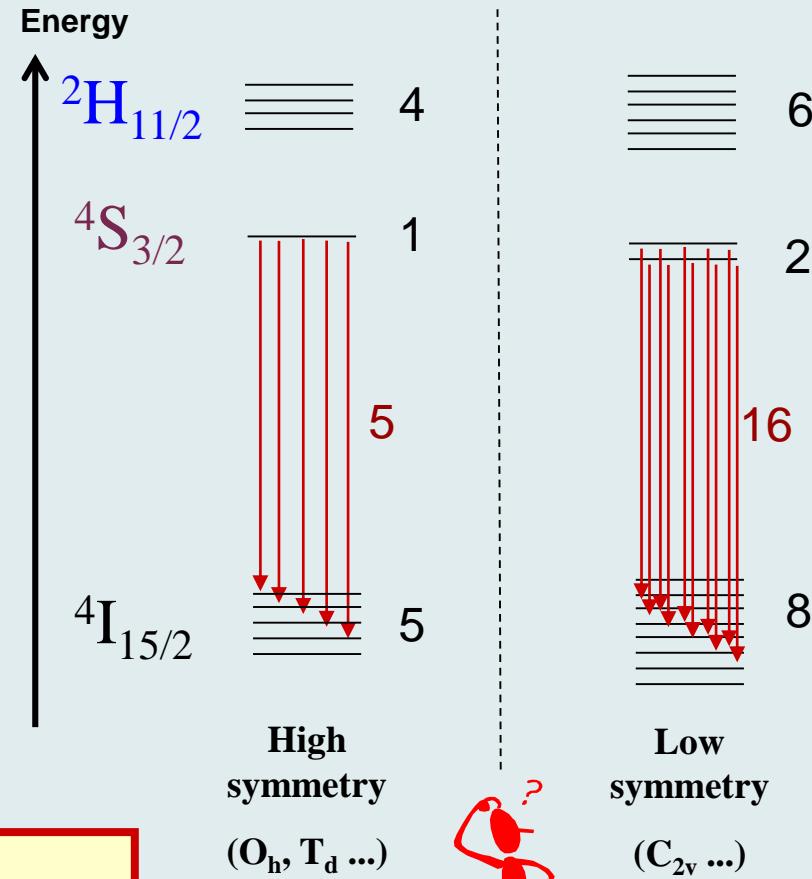
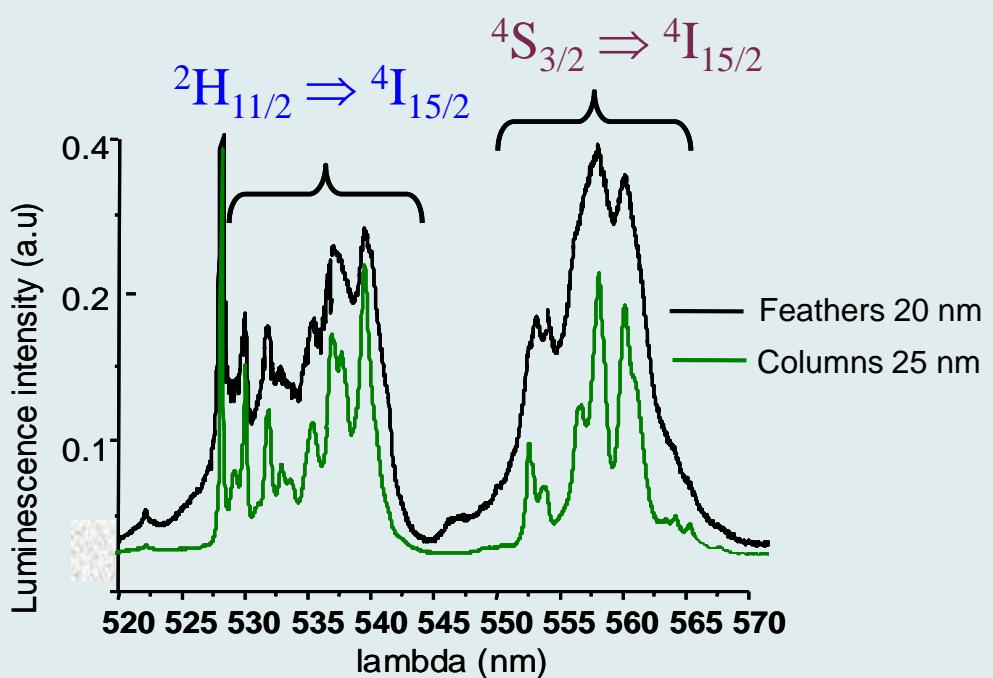


Evolution of Er visible luminescence as a function of AlN structure



$\lambda_i = 514 \text{ nm (2.4 eV)}$

Contributions > 5 !

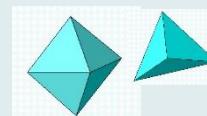


Er cations are on:

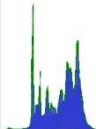
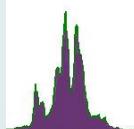
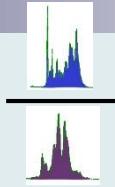
1 low symmetry site (all contributions not resolved)

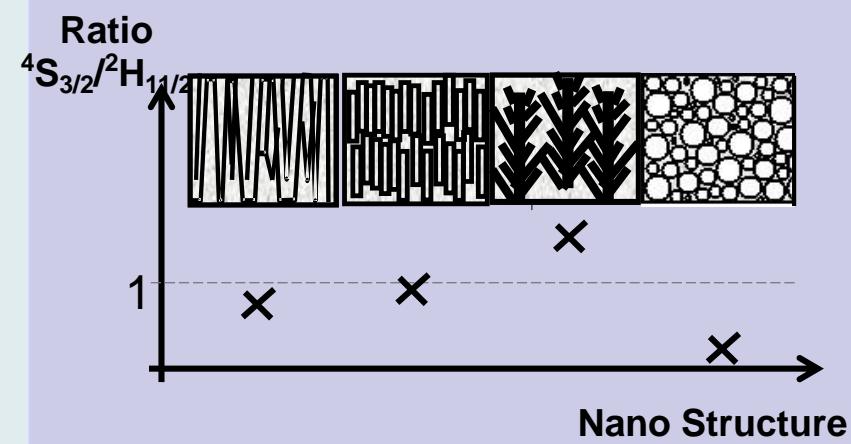
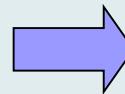
or 2 high symmetry sites (superimposed contributions)

=> Further experiments to conclude



Integrated areas

			
Sample	$^2\text{H}_{11/2} \Rightarrow ^4\text{I}_{15/2}$ (528-545nm)	$^4\text{S}_{3/2} \Rightarrow ^4\text{I}_{15/2}$ (545-570nm)	ratio $^4\text{S}_{3/2}/^2\text{H}_{11/2}$
Nano columns 16 nm	1,28	1,09	0,85
Nano rods 20 nm	1,41	1,37	0,97
Nano "feathers" 20 nm	2,22	2,90	1,31
Nano grains 3nm	2,07	0,56	0,27



→ Er can trace the nano-structure, as Eu in glasses *

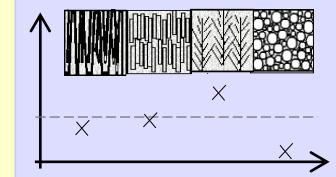
* G. Vicentini, et al. Coord. Chem. Rev. (2000)

To summarize:

Er Tracer of the nano-structure : Probe of disorder

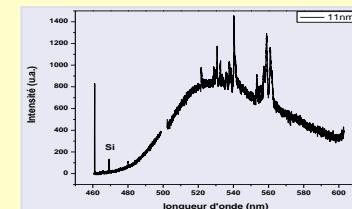
Need of further experiment to identify the Er site:

- Site selective photoluminescence



Coïncidence of visible PL of nano AlN and Er:

- AlN matrix : **broad** band centered around 530 nm
- Er : 520 - 570 nm



Possibility of energy transfer for IR 1.54 μm Er PL ?

Nano AlN may become a RE sensitizer

Need of further experiment to confirm

- Low temperature PL measurement ?
- Life time measurement : which kind of decay ?

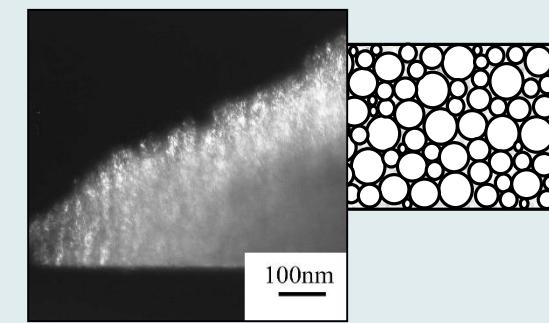
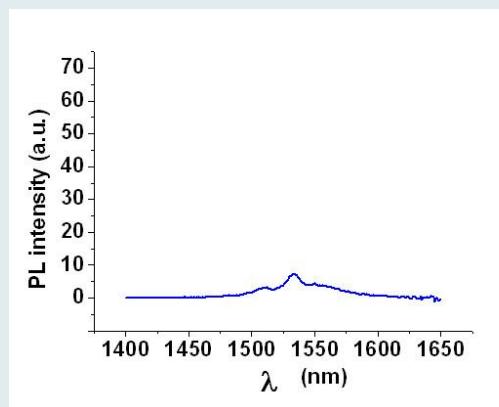
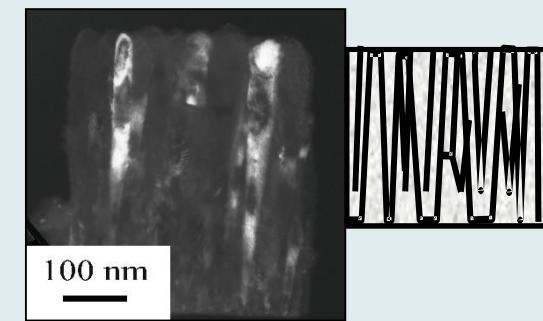
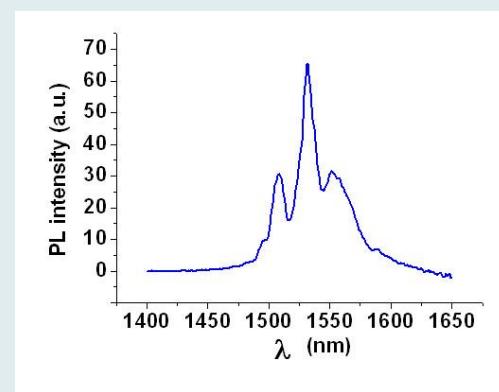


Recent result:

INFRA RED 1.54 μ m luminescence measurement versus 2 structures



$$\lambda_i = 325 \text{ nm (3.8 eV)}$$



*Thank you
for your attention*



Place Stanislas, Nancy, France